

L Number	Hits	Search Text	DB	Time stamp
3	22	integrated with circuit with decoupling with capacitor.ti.	USPAT; US-PGPUB; JPO	2004/07/15 08:06
4	0	(integrated with circuit with decoupling with capacitor.ti.) and(float\$3 adj drain)	USPAT; US-PGPUB; JPO	2004/07/15 08:07
5	2	(integrated with circuit with decoupling with capacitor.ti.) and(drain)	USPAT; US-PGPUB; JPO	2004/07/15 08:10
6	0	decoupling with capacitor.ti. and(float\$3 adj drain)	USPAT; US-PGPUB; JPO	2004/07/15 08:10
7	14	decoupling with capacitor.ti. and(drain)	USPAT; US-PGPUB; JPO	2004/07/15 08:11
8	6	(decoupling with capacitor.ti. and(drain)) and(electrode)	USPAT; US-PGPUB; JPO	2004/07/15 08:11
9	6	((decoupling with capacitor.ti. and(drain)) and(electrode)) and(source)	USPAT; US-PGPUB; JPO	2004/07/15 08:15
10	131	mos with capacitor.ti.	USPAT; US-PGPUB; JPO	2004/07/15 08:15
11	2027	semiconductor with capacitor.ti.	USPAT; US-PGPUB; JPO	2004/07/15 08:15
12	86	(mos with capacitor.ti.) and(electrode)	USPAT; US-PGPUB; JPO	2004/07/15 08:16
13	49	((mos with capacitor.ti.) and(electrode)) and(drain and source)	USPAT; US-PGPUB; JPO	2004/07/15 09:09
14	383	(semiconductor with capacitor.ti.) and(drain adj region)	USPAT; US-PGPUB; JPO	2004/07/15 08:21
15	218	((semiconductor with capacitor.ti.) and(drain adj region)) and(source adj region)	USPAT; US-PGPUB; JPO	2004/07/15 08:21
16	211	((semiconductor with capacitor.ti.) and(drain adj region)) and(source adj region) and(electrode)	USPAT; US-PGPUB; JPO	2004/07/15 08:21
17	188	((semiconductor with capacitor.ti.) and(drain adj region)) and(source adj region) and(electrode) and(dielectric)	USPAT; US-PGPUB; JPO	2004/07/15 08:22
18	0	((semiconductor with capacitor.ti.) and(drain adj region)) and(source adj region) and(electrode) and(dielectric) and(BJT)	USPAT; US-PGPUB; JPO	2004/07/15 08:22
19	174	((semiconductor with capacitor.ti.) and(drain adj region)) and(source adj region) and(electrode) and(dielectric) and(transistor)	USPAT; US-PGPUB; JPO	2004/07/15 08:22
20	2	"5371396" and(capacitor)	USPAT; US-PGPUB; JPO	2004/07/15 09:17
21	14	"6034388"	USPAT; US-PGPUB; JPO	2004/07/15 09:33
22	278	plurality with decoupling with capacitor	USPAT; US-PGPUB; JPO	2004/07/15 10:08
23	15	plurality near decoupling near capacitor	USPAT; US-PGPUB; JPO	2004/07/15 09:34
24	0	multi-fingered with decoupling adj capacitor	USPAT; US-PGPUB; JPO	2004/07/15 09:35
25	0	fingered with decoupling adj capacitor	USPAT; US-PGPUB; JPO	2004/07/15 09:35

26	0	decoupling adj capacitor.ti. and(BJT)	USPAT; US-PGPUB; JPO	2004/07/15 09:36
27	0	decoupling adj capacitor.ti. and(parasitic near function)	USPAT; US-PGPUB; JPO	2004/07/15 09:36
28	3	decoupling adj capacitor.ti. and(bipolar near transistor)	USPAT; US-PGPUB; JPO	2004/07/15 10:08
29	19	plurality with capacitor.ti.	USPAT; US-PGPUB; JPO	2004/07/15 10:10
30	144	361/306.2 and(plurality with capacitor)	USPAT; US-PGPUB; JPO	2004/07/15 10:17
31	235	integrated with circuit.ti. and(decoupling adj capacitor)	USPAT; US-PGPUB; JPO	2004/07/15 10:17
32	152	(integrated with circuit.ti. and(decoupling adj capacitor)) and(source)	USPAT; US-PGPUB; JPO	2004/07/15 10:18
33	78	((integrated with circuit.ti. and(decoupling adj capacitor)) and(source)) and(drain)	USPAT; US-PGPUB; JPO	2004/07/15 10:18
34	35	((integrated with circuit.ti. and(decoupling adj capacitor)) and(source)) and(drain)) and(electrode)	USPAT; US-PGPUB; JPO	2004/07/15 10:18